

Printed Pages: 3

TEE - 403

(Following Paper ID and			-	
PAPER ID: 2053	Roll No.			

B. Tech.

(SEM. IV) EXAMINATION, 2007-08 ELECTRICALS & ELECTRONICS ENGINEERING MATERIALS

Time: 3 Hours]

[Total Marks: 100

Note:

- (1) Attempt all questions.
- (2) All questions carry equal marks.
- 1 Attempt any **four** parts of the following:

 4×5

- (a) Describe briefly the basic seven crystal systems.
- (b) Define the following:
 - (i) Unit cell
 - (ii) Space lattice
 - (iii) Body centered cubic structure.
- (c) State and explain Bragg's law. How it can be used to determine lattice parameters?
- (d) What is `Atomic Packing Factor? Calculate its value for simple cube and body centered cube structure.
- (e) Derive the relation between interplanar spacing d' and cube edge `a'.
- (f) Draw the following directions in a face centered cubic structure (112), (001) and (101)

2 Attempt any four parts of the following:

- (a) Explain Seeback, Peltier and Thomson effects.
- (b) Explain Superconductivity. What is the effect of magnetic field on the superconductors?
- (c) Derive an expression for heat development in a current carrying conductor. Also explain the factors responsible for it.
- (d) Determine the temperature coefficient of resistance of material used in a resistor if the resistance at 25°C is 50 ohms and at 70°C is 57.2 ohms.
- (e) In a certain copper conductor, the current density is 2.4 A/mm^2 and electron density is 5×10^{28} free electrons per m³ of the copper. Determine the drift velocity of the electrons. Given $e=1.6 \times 10^{-19}$ coulomb.
- (f) Explain the factors which affect the resistivity of conducting materials.
- 3 Attempt any two parts of the following.

2×10

- (a) Describe various mechanisms of dielectric polarisation and derive an expression for electronic polarizability.
- (b) What is dielectric loss and loss angle? How do loss factor and dielectric constant vary with temperature and frequency of an alternating field? Explain.
- (c) Explain with examples:
 - (i) Piezoelectricity and
 - (ii) Ferroelectricity.

- (a) What is Hall Effect? Explain its origin and derive the relation between Hall coefficient and carrier density.
- (b) (i) Discuss in brief the mechanism of conduction in N-type and P-type semiconductors.
 - (ii) Differentiate between intrinsic and extrinsic semiconductors.
- (c) (i) Explain in brief P-N-P and N-P-N transistors.
 - (ii) Give constructional details of Junction Field Effect Transistors (JFET).
- 5 Attempt any **two** parts of the following:

 2×10

- (a) Explain the phenomenon of
 - (i) magnetostriction and
 - (ii) hysteresis in ferromagnetic materials
- (b) How do you classify the materials as dia, para or ferromagnetic? Explain ferromagnetism and antiferromagnetism.
- (c) (i) Differentiate between soft and hard magnetic materials.
 - (ii) Explain briefly following mechanical properties of metals:Elasticity, Plasticity, Ductility and Malleability.